
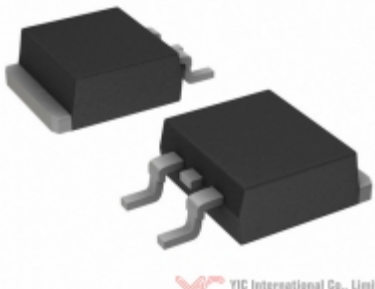







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|---|---|
|  | <h2 style="color: red;">FQB27P06TM</h2> <p>Hersteller-Teilenummer: FQB27P06TM</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 60V 27A D2PAK</p> <p>Datenblätter:  FQB27P06TM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 6492 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
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| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|--|---|
| Teilenummer | FQB27P06TM |
| Hersteller | Fairchild/ON Semiconductor |
| Beschreibung | MOSFET P-CH 60V 27A D2PAK |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs , |
| Teilstatus | 6492 pcs Stock |
| Serie | QFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB |
| Supplier Device-Gehäuse | D ² PAK (TO-263AB) |
| Verlustleistung (max) | 3.75W (Ta), 120W (Tc) |
| Typ FET | P-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 60V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 27A (Tc) |
| Rds On (Max) @ Id, Vgs | 70 mOhm @ 13.5A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 43nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 1400pF @ 25V |
| Antriebsspannung (Max Rds On, Min Rds On) | 10V |
| Vgs (Max) | ±25V |
| Verpackung | Tape & Reel (TR) |












FQB27P06TM ist neu im Original, Suche FQB27P06TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB27P06TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB27P06TM: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|--|---|--|
|  <p>FQB2N30TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 300V 2.1A D2PAK</p> |  <p>FQB2N50C VB FQB2N50C VB</p> |  <p>FQB27N25TM_AM002 AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 25.5A D2PAK</p> |  <p>FQB27P06 F FQB27P06 F</p> |
|  <p>FQB27P06TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 27A D2PAK</p> |  <p>FQB2N30TM Fairchild/ON Semiconductor MOSFET N-CH 300V 2.1A D2PAK</p> |  <p>FQB27N25TM_AM002 Fairchild/ON Semiconductor MOSFET N-CH 250V 25.5A D2PAK</p> |  <p>FQB27N25TM-F085 AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 25.5A 131M</p> |

heiße Teile

Mehr

| | | | | |
|---|---|--|--|---|
|  FQB19N20CTM |  FQB19N20CTM |  FQB19N20L |  FQB19N20LTM |  FQB19N20LTM |
|  FQB19N20TM |  FQB19N20TM |  FQB1N60TM |  FQB1N60TM |  FQB20N06L |
|  FQB20N60FTM |  FQB20N60TM |  FQB22P10 |  FQB22P10TM |  FQB22P10TM |
|  FQB22P10TM_F085 |  FQB24N08TM |  FQB24N08TM |  FQB25N33 |  FQB25N33TM |
|  FQB25N33TM |  FQB25N33TM_F085 |  FQB27N25TM |  FQB27P06 |  FQB27P06TM |
|  FQB2N50C |  FQB2N60TM |  FQB2N60TM |  FQB2N80TM |  FQB2N80TM |
|  FQB2NA90TM |  FQB2NA90TM |  FQB2P25TM |  FQB2P25TM |  FQB30N06 |
|  FQB30N06L |  FQB30N06LTM |  FQB30N06LTM |  FQB30N06TM |  FQB30N06TM |
|  FQB32N12V2 |  FQB32N12V2TM |  FQB32N12V2TM |  FQB32N20 |  FQB32N20C |
|  FQB32N20CTM |  FQB32N20CTM |  FQB32N30 |  FQB33N10 |  FQB33N10L |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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